NSN 5962-01-360-3296

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-360-3296

Body Length:
Between 0.640 inches and 0.660 inches
Body Width:
Between 0.541 inches and 0.561 inches
Body Height:
Between 0.080 inches and 0.100 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Programmable and erasable and w/enable and w/disable and bidirectional
Inclosure Material:
Ceramic
Inclosure Configuration:
Pin grid array
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
26 input
Current Rating Per Characteristic:
80.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.3 volts power source and 6.25 volts power source
Capitance Rating Per Characteristic:
10.00 input picofarads and 10.00 output picofarads
Time Rating Per Chacteristic:
250.00 nanoseconds propagation delay
Memory Device Type:
Eeprom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 pin
Shelf Life:
N/a
Unit Of Measure:

--

NSN 5962-01-360-3296

Memory Microcircuit - Page 2 of 2



Demilitarization:

No

Fiig:

A458a0